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# 2SC4537

Silicon NPN Epitaxial

# HITACHI

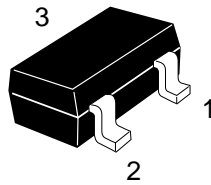
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## Application

UHF / VHF wide band amplifier

## Outline

CMPAK



1. Emitter
2. Base
3. Collector

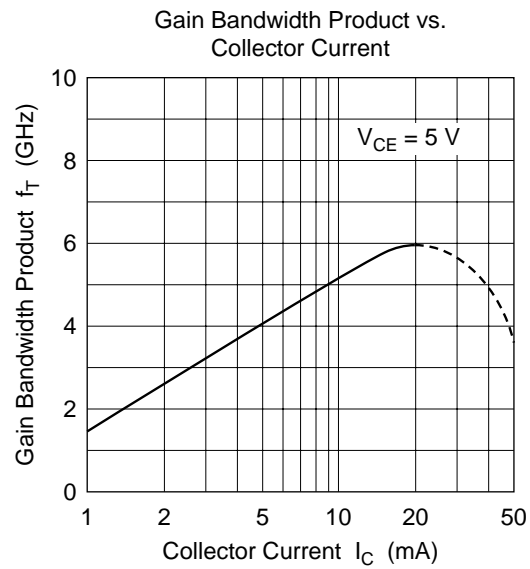
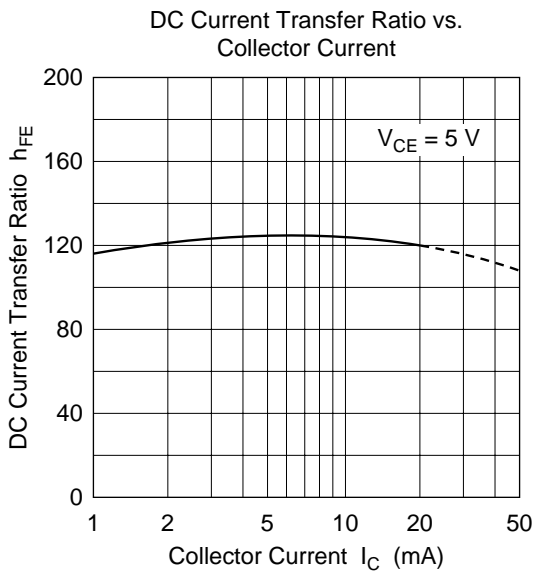
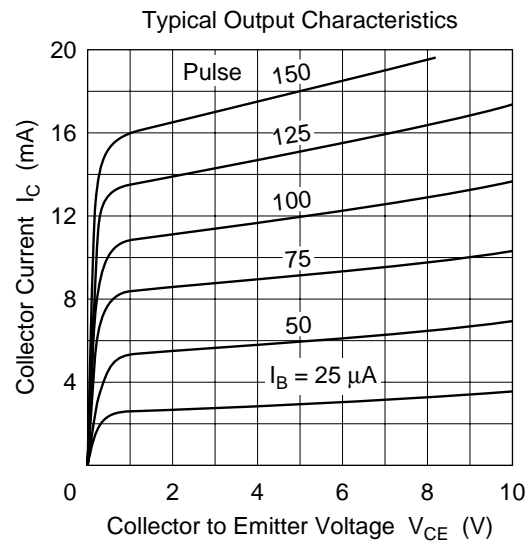
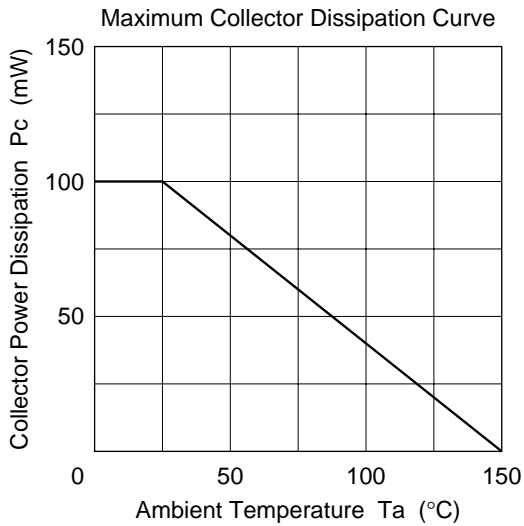
**Absolute Maximum Ratings** ( $T_a = 25^\circ\text{C}$ )

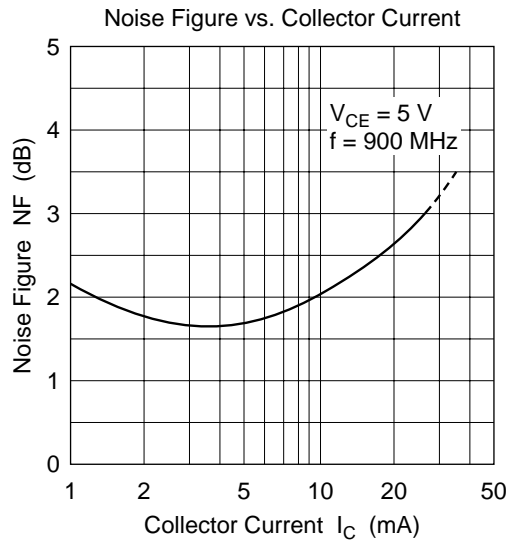
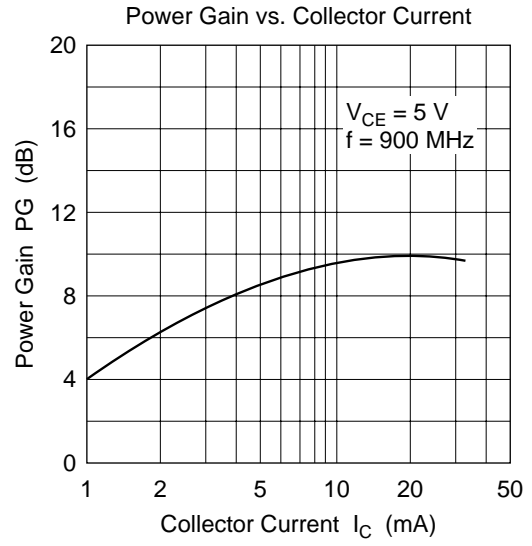
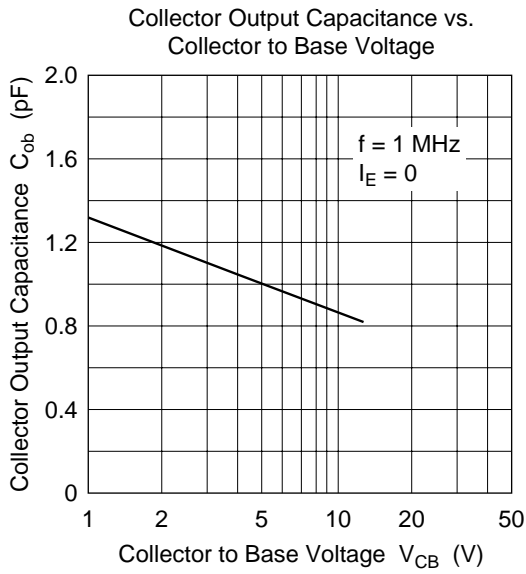
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{\text{CBO}}$	15	V
Collector to emitter voltage	$V_{\text{CEO}}$	11	V
Emitter to base voltage	$V_{\text{EBO}}$	2	V
Collector current	$I_{\text{C}}$	50	mA
Collector power dissipation	$P_{\text{C}}$	100	mW
Junction temperature	$T_{\text{j}}$	150	$^\circ\text{C}$
Storage temperature	$T_{\text{stg}}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_a = 25^\circ\text{C}$ )

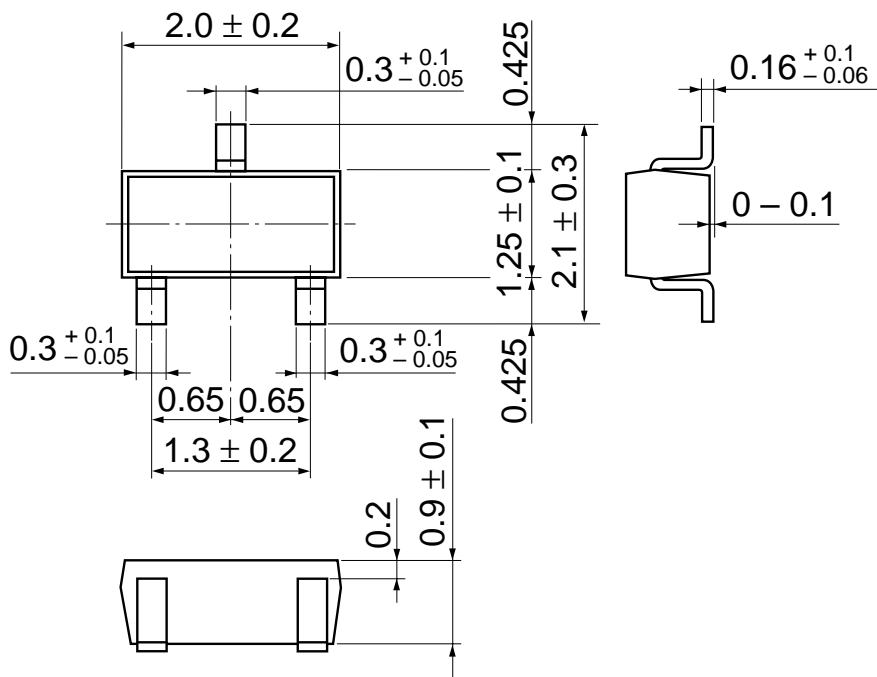
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	15	—	—	V	$I_{\text{C}} = 10 \mu\text{A}$ , $I_{\text{E}} = 0$
Collector cutoff current	$I_{\text{CBO}}$	—	—	1	$\mu\text{A}$	$V_{\text{CB}} = 12 \text{ V}$ , $I_{\text{E}} = 0$
Collector cutoff current	$I_{\text{CEO}}$	—	—	1	$\mu\text{A}$	$V_{\text{CE}} = 10 \text{ V}$ , $I_{\text{E}} = \infty$
Emitter cutoff current	$I_{\text{EBO}}$	—	—	1	$\mu\text{A}$	$V_{\text{EB}} = 1 \text{ V}$ , $I_{\text{C}} = 0$
DC current transfer ratio	$h_{\text{FE}}$	50	120	250	—	$V_{\text{CE}} = 5 \text{ V}$ , $I_{\text{C}} = 20 \text{ mA}$
Collector output capacitance	$C_{\text{ob}}$	—	1.0	1.5	pF	$V_{\text{CB}} = 5 \text{ V}$ , $I_{\text{E}} = 0$ , $f = 1\text{MHz}$
Gain bandwidth product	$f_{\text{T}}$	4.5	6.0	—	GHz	$V_{\text{CE}} = 5 \text{ V}$ , $I_{\text{C}} = 20 \text{ mA}$
Power gain	PG	—	10	—	dB	$V_{\text{CE}} = 5 \text{ V}$ , $I_{\text{C}} = 20 \text{ mA}$ , $f = 900 \text{ MHz}$
Noise figure	NF	—	1.6	—	dB	$V_{\text{CE}} = 5 \text{ V}$ , $I_{\text{C}} = 5 \text{ mA}$ , $f = 900 \text{ MHz}$

Note: Marking is "IS—".





Unit: mm



Hitachi Code	CMPAK
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.006 g

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